# **MA4X159A** (MA159A)

## Silicon epitaxial planar type

### For switching circuits

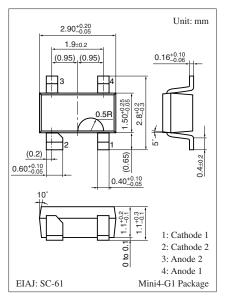
#### ■ Features

- Two isolated elements contained in one package, allowing highdensity mounting
- Short reverse recovery time t<sub>rr</sub>
- Small terminal capacitance C<sub>t</sub>

## ■ Absolute Maximum Ratings $T_a = 25$ °C

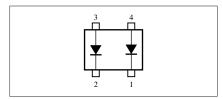
| Parameter                    |        | Symbol         | Rating      | Unit |
|------------------------------|--------|----------------|-------------|------|
| Reverse voltage              |        | $V_R$          | 80          | V    |
| Maximum peak reverse voltage |        | $V_{RM}$       | 80          | V    |
| Forward current              | Single | $I_{F}$        | 100         | mA   |
|                              | Double |                | 75          |      |
| Peak forward                 | Single | $I_{FM}$       | 225         | mA   |
| current                      | Double |                | 170         |      |
| Non-repetitive peak          | Single | $I_{FSM}$      | 500         | mA   |
| forward surge current *      | Double |                | 375         |      |
| Junction temperature         |        | T <sub>j</sub> | 150         | °C   |
| Storage temperature          |        | $T_{stg}$      | -55 to +150 | °C   |

Note) \*: t = 1 s



Marking Symbol: M1B

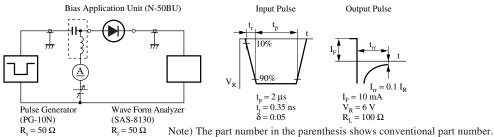
#### Internal Connection



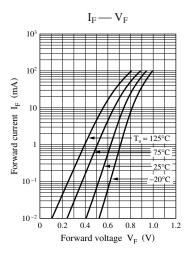
## ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

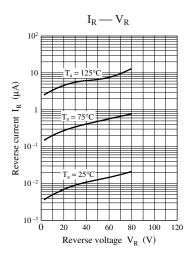
| Parameter               | Symbol          | Conditions                               | Min | Тур  | Max  | Unit |
|-------------------------|-----------------|--|-----|------|------|------|
| Forward voltage         | V <sub>F</sub>  | $I_F = 100 \text{ mA}$                   |     | 0.95 | 1.20 | V    |
| Reverse voltage         | $V_R$           | $I_R = 100 \mu A$                        | 80  |      |      | V    |
| Reverse current         | $I_R$           | V <sub>R</sub> = 75 V                    |     |      | 100  | nA   |
| Terminal capacitance    | C <sub>t</sub>  | $V_R = 0 \text{ V, f} = 1 \text{ MHz}$   |     | 0.9  | 2.0  | pF   |
| Reverse recovery time * | t <sub>rr</sub> | $I_F = 10 \text{ mA}, V_R = 6 \text{ V}$ |     |      | 3    | ns   |
|                         |                 | $I_{rr} = 0.1 I_{R}, R_{L} = 100 \Omega$ |     |      |      |      |

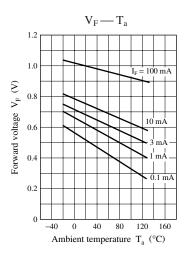
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. Absolute frequency of input and output is 100 MHz.
  - 3. \*: t<sub>rr</sub> measurement circuit

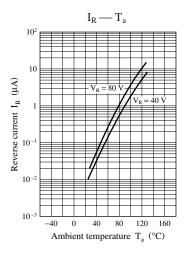


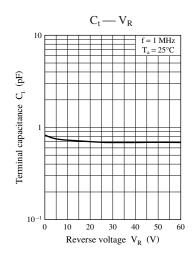
## **Panasonic**

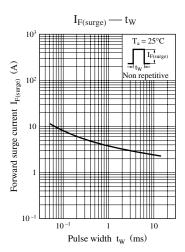












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